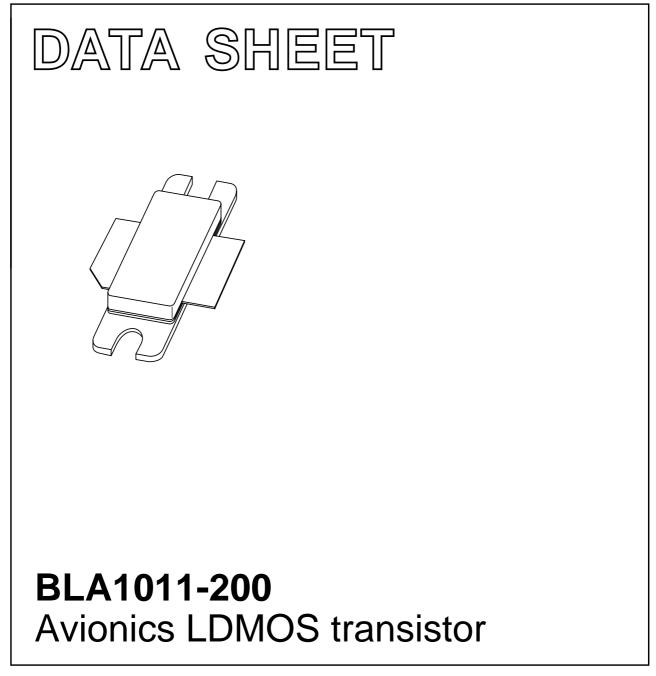
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2001 May 15 2002 Mar 18



FEATURES

- High power gain
- · Easy power control
- Excellent ruggedness
- Source on mounting base eliminates DC isolators, reducing common mode inductance.

APPLICATIONS

• Avionics transmitter applications in the 1030 to 1090 MHz frequency range.

DESCRIPTION

Silicon N-channel enhancement mode lateral D-MOS transistor encapsulated in a 2-lead SOT502A flange package with a ceramic cap. The common source is connected to the mounting flange.

QUICK REFERENCE DATA

RF performance at T_h = 25 °C in a common source test circuit.

PINNING -	SOT502A
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PIN	DESCRIPTION
1	drain
2	gate
3	source, connected to flange

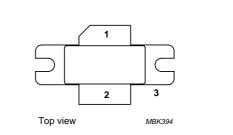


Fig.1 Simplified outline SOT502A.

MODE OF OPERATION	f	V _{DS}	P _L	G _p	η _D	t _r	t _f
	(MHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
Pulsed class-AB; $t_p = 50 \ \mu s; \ \delta = 2 \ \%$	1030 to 1090	36	200	>13; typ. 15	>45; typ. 50	<50; typ. 35	<50; typ. 6

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		_	75	V
V _{GS}	gate-source voltage		_	±22	V
P _{tot}	total power dissipation	$T_h \le 25 \ ^\circ C$; $t_p = 50 \ \mu s$; $\delta = 2 \ \%$	-	700	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	200	°C

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Z _{th j-h}	thermal impedance from junction to heatsink	T _h = 25 °C; note 1	0.15	K/W

Note

1. Thermal resistance is determined under RF operating conditions; $t_p = 50 \ \mu s$, $\delta = 10 \ \%$.

CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0; I_D = 3 \text{ mA}$	75	-	-	V
V _{GSth}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 300 mA	4	-	5	V
I _{DSS}	drain-source leakage current	V _{GS} = 0; V _{DS} = 36 V	-	-	1	μA
I _{DSX}	on-state drain current	$V_{GS} = V_{GSth} + 9 V; V_{DS} = 10 V$	45	-	-	А
I _{GSS}	gate leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0$	-	-	1	μA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 10 A	-	9	-	S
R _{DSon}	drain-source on-state resistance	V _{GS} = 9 V; I _D = 10 A	_	60	-	mΩ

APPLICATION INFORMATION

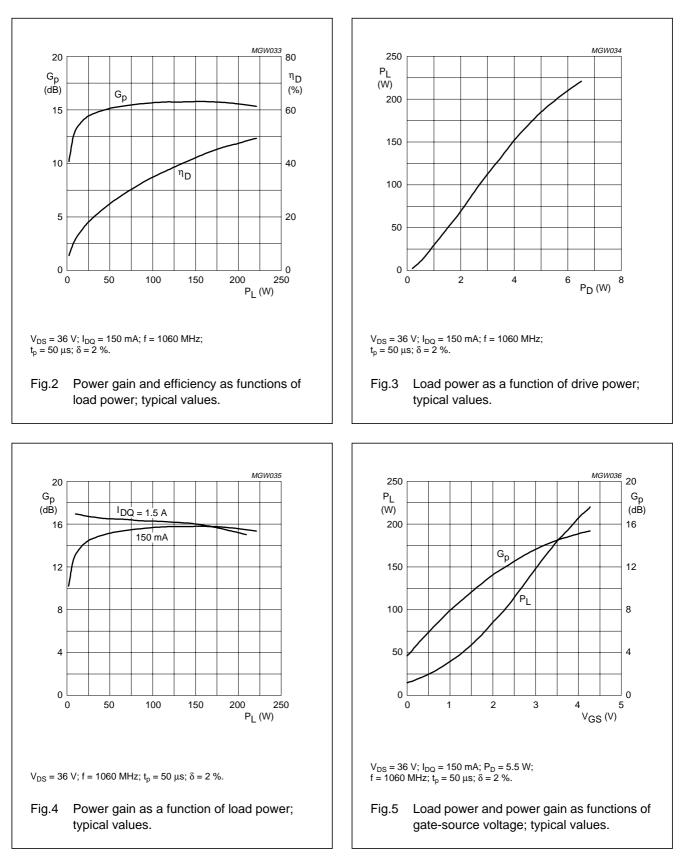
RF performance in a common source class-AB circuit. T_h = 25 °C; $Z_{th mb-h}$ = 0.15 K/W; unless otherwise specified.

MODE OF OPERATION	f	V _{DS}	P _L	G _p	ղը	t _r	t _f
	(MHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
Pulsed class-AB; $t_p = 50 \ \mu s; \ \delta = 2 \ \%$	1030 to 1090	36	200	>13; typ. 15	>45; typ. 50	<50; typ. 35	<50; typ. 6

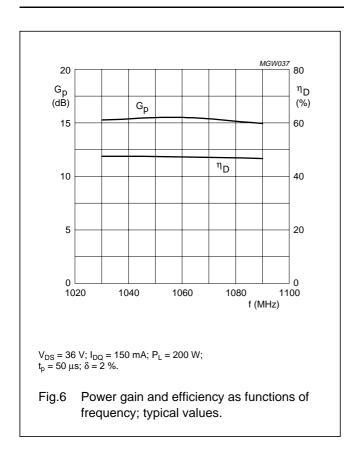
Ruggedness in class-AB operation

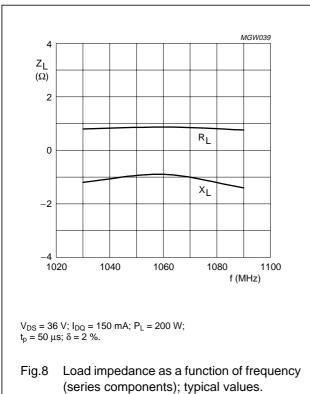
The BLA1011-200 is capable of withstanding a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions: V_{DS} = 36 V; f = 1030 to 1090 MHz at rated load power.

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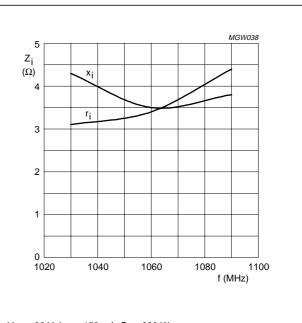
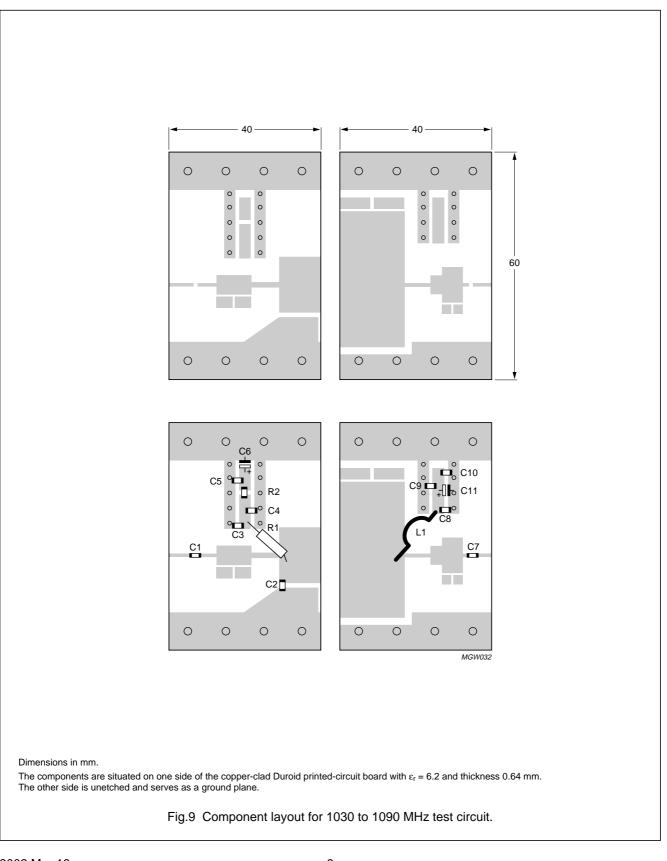


Fig.7 Input impedance as a function of frequency (series components); typical values.

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List of components (see Fig.9)

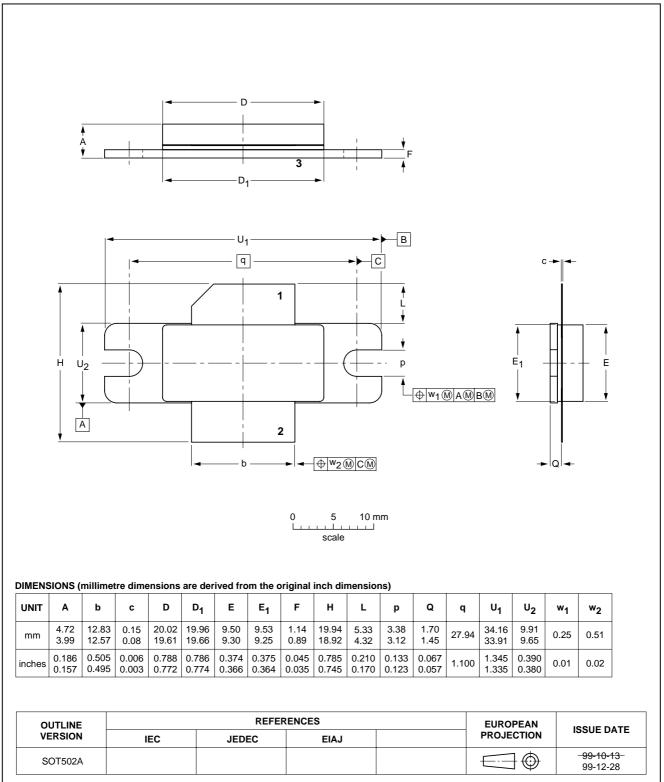
COMPONENT	DESCRIPTION	VALUE	DIMENSIONS
C1	multilayer ceramic chip capacitor; note 1	39 pF	
C2	multilayer ceramic chip capacitor; note 2	4.3 pF	
C3	multilayer ceramic chip capacitor; note 1	11 pF	
C4, C7	multilayer ceramic chip capacitor; note 1	62 pF	
C5	multilayer ceramic chip capacitor; note 1	100 pF	
C6	electrolytic capacitor	47 μF; 20 V	
C8	multilayer ceramic chip capacitor; note 2	20 pF	
C9	multilayer ceramic chip capacitor; note 1	47 pF	
C10	multilayer ceramic chip capacitor; note 3	1.2 nF	
C11	electrolytic capacitor	47 μF; 63 V	
L1	Ω -shaped enamelled 1 mm copper wire		length = 38 mm
R1	metal film resistor	301 Ω	
R2	SMD0508 resistor	18 Ω	

Notes

- 1. American Technical Ceramics type 100A or capacitor of same quality.
- 2. American Technical Ceramics type 100B or capacitor of same quality.
- 3. American Technical Ceramics type 700 or capacitor of same quality.

PACKAGE OUTLINE

Flanged LDMOST ceramic package; 2 mounting holes; 2 leads



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SOT502A

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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

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NOTES

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NOTES

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Contact information

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